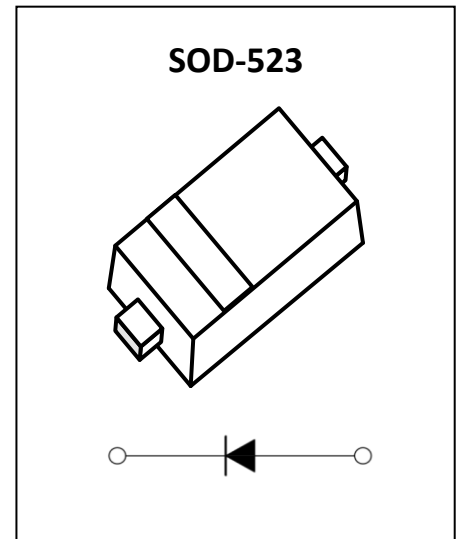


**1N4148WT Fast Switching Diodes**
**Feature**

- $V_R$  75V
- $I_{FAV}$  150mA

**Application**

- Extreme fast switches

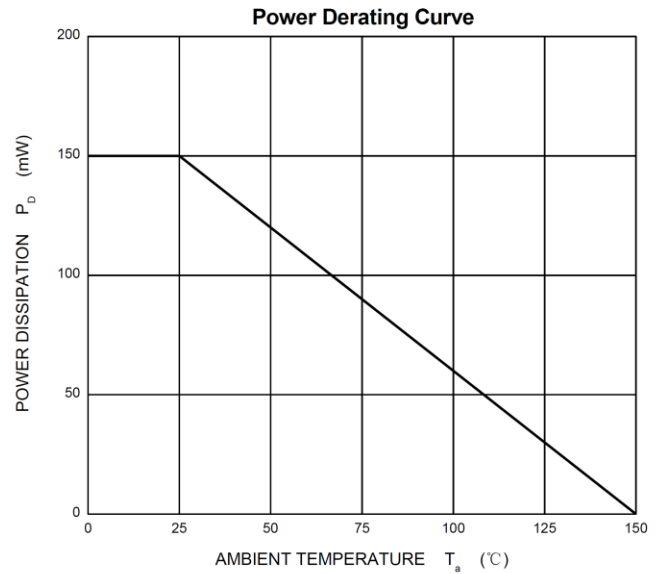
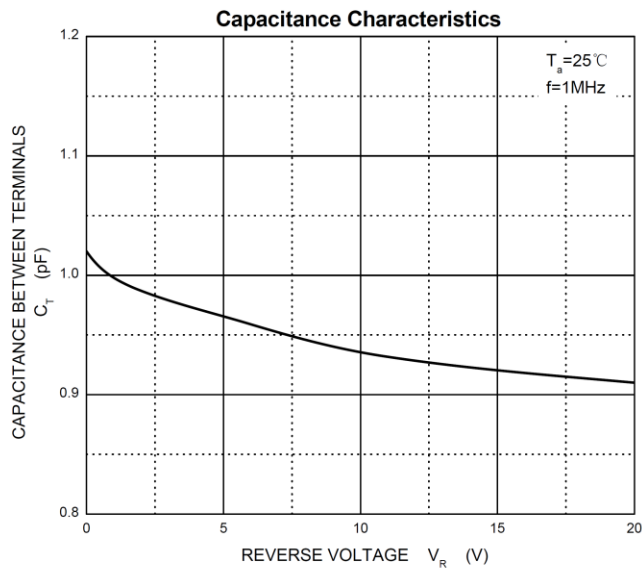
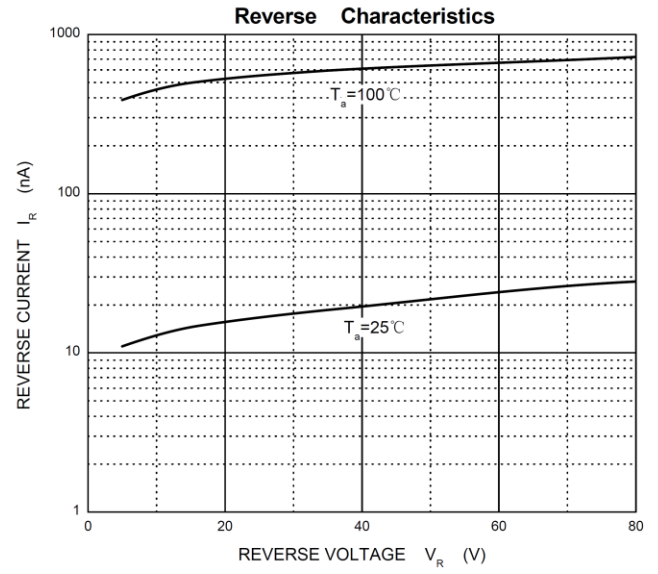
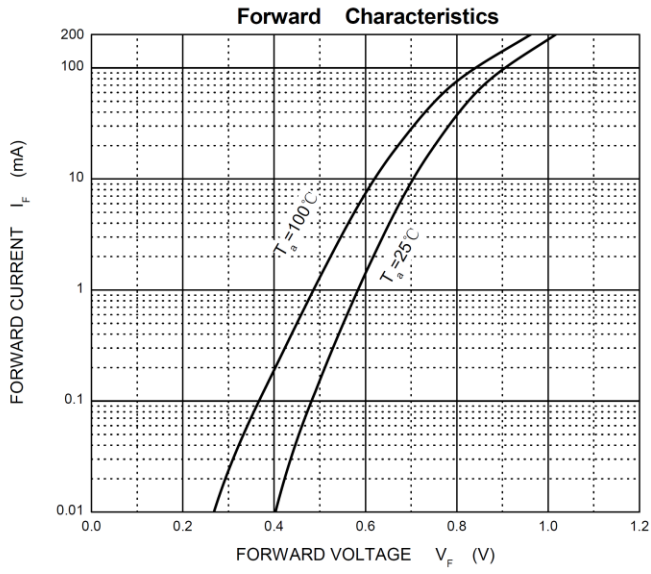
**MARKING:**

**ABSOLUTE MAXIMUM RATINGS ( $T_A=25^\circ\text{C}$  unless otherwise noted)**

Parameter	Symbol	Value	Unit
Non-Repetitive Peak Reverse Voltage	$V_{RSM}$	100	V
Repetitive Peak Reverse Voltage	$V_{RRM}$	75	V
Average rectified output current	$I_o$	0.15	A
Forward continuous current	$I_{FM}$	0.30	A
Non-repetitive Peak Forward Surge Current @ $t=8.3$ ms	$I_{FSM}$	2	A
Power Dissipation	$P_D$	0.15	W
Junction Temperature	$T_J$	150	$^\circ\text{C}$
Storage Temperature	$T_{STG}$	-65 ~ +150	$^\circ\text{C}$

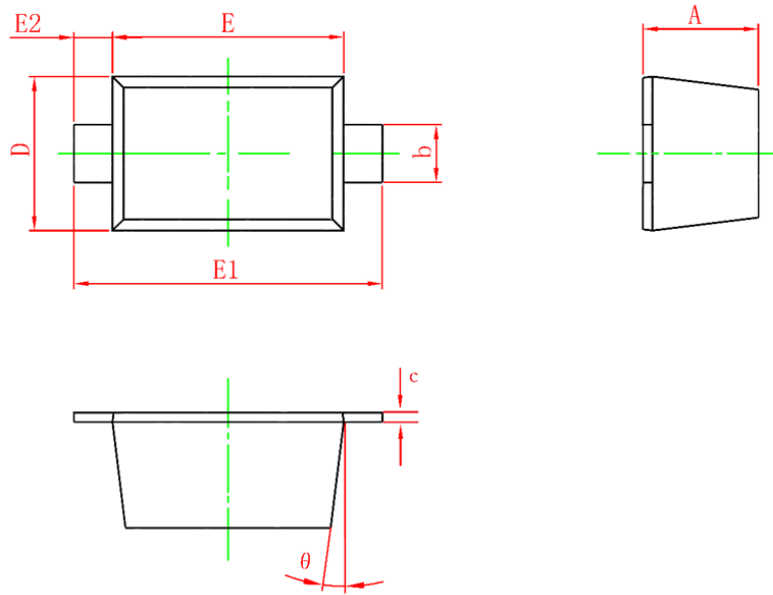
**ELECTRICAL CHARACTERISTICS ( $T_A=25^\circ\text{C}$  unless otherwise noted)**

Parameter	Symbol	Test Condition	Min	Max	Unit
Forward voltage	$V_F$	$I_F = 1\text{mA}$		0.715	V
		$I_F = 10\text{mA}$		0.855	V
		$I_F = 50\text{mA}$		1.0	V
		$I_F = 150\text{mA}$		1.25	V
Reverse current	$I_R$	$V_R = 20\text{V}$		25	nA
		$V_R = 75\text{V}$		1	$\mu\text{A}$
Diode capacitance	$C_D$	$V_R = 0\text{V}$ , $f = 1\text{MHz}$		2	pF
Reverse Recovery Time	$t_{rr}$	$I_F = I_R = 10\text{mA}$ , $I_{rr} = 0.1 \cdot I_R$ , $R_L = 100\Omega$		4	ns

**Typical Electrical and Thermal Characteristics**



## SOD-523 Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.470	0.770	0.018	0.030
b	0.250	0.350	0.010	0.014
c	0.080	0.150	0.003	0.006
D	0.750	0.850	0.030	0.033
E	1.100	1.300	0.043	0.051
E1	1.500	1.700	0.059	0.067
E2	0.200REF		0.008REF	
θ	7°REF		7°REF	